

SILICON POWER TRANSISTOR 2SA1652

PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SA1652 is a mold power transistor developed for highspeed switching and features a very low collector-to-emitter saturation. This transistor is ideal for use in switching power supplies, DC/DC converters, motor drivers, solenoid drivers, and other low-voltage power supply devices, as well as for high-current switching.

FEATURES

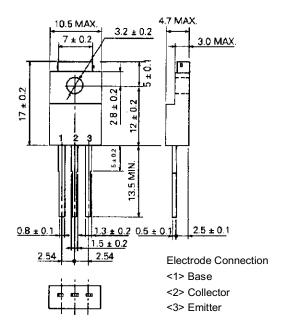
- Mold package that does not require an insulating board or insulation bushing
- · Fast switching speed
- Low collector-to-emitter saturation voltage: $V_{CE(sat)} \le -0.3 \text{ V (MAX.)} @Ic = -6 \text{ A}$

QUALITY GRADES

Standard

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

PACKAGE DRAWING (UNIT: mm)



ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	Vсво		-150	V
Collector to emitter voltage	VCEO		-100	V
Emitter to base voltage	VEBO		-7.0	٧
Collector current	Ic(DC)		-10	Α
Collector current	IC(pulse)	PW ≤ 300 µs, duty cycle ≤ 10%	-20	Α
Base current	I _{B(DC)}		-6.0	Α
Total power dissipation	Рт	Tc = 25°C	25	W
Total power dissipation	PT	Ta = 25°C	2.0	W
Junction temperature	Tj		150	°C
Storage temperature	Tstg		-55 to +150	°C

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ELECTING A 6.5 CHARAGTERISTICS (Ta = 25°C)

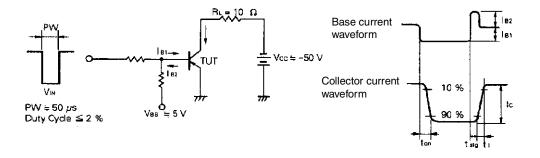
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = -100 V, IE = 0			-10	μΑ
Emitter cutoff current	ІЕВО	V _{EB} = -5 V, I _C = 0			-10	μΑ
DC current gain	h _{FE1} *	$V_{CE} = -2 \text{ V, Ic} = -0.5 \text{ A}$	100			-
DC current gain	hFE2*	Vce = -2 V, Ic = -2 A	100		400	_
DC current gain	h _{FE3} *	Vce = -2 V, Ic = -6 A	60			-
Collector saturation voltage	V _{CE(sat)1} *	$I_C = -6 \text{ A}, I_B = -0.3 \text{ A}$			-0.3	V
Collector saturation voltage	VCE(sat)2*	$I_C = -8 \text{ A}, I_B = -0.4 \text{ A}$			-0.5	V
Base saturation voltage	V _{BE(sat)1} *	Ic = -6 A, I _B = -0.3 A			-1.2	V
Base saturation voltage	V _{BE(sat)2} *	$I_C = -8 \text{ A}, I_B = -0.4 \text{ A}$			-1.5	V
Gain bandwidth product	f⊤	Vce = -10 V, Ic = -0.5 A		150		MHz
Collector capacitance	Cob	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		250		pF
Turn-on time	ton	Ic = -6 A, IB ₁ = $-$ IB ₂ = -0.3 A, RL = 8.3Ω , Vcc = $-50 V$ Refer to the test circuit.		0.3		μs
Storage time	tstg			1.5		μs
Fall time	t f	Tiolor to the test offenit.		0.4		μs

^{*} Pulse test PW \leq 350 μ s, duty cycle \leq 2%

hfe CLASSIFICATION

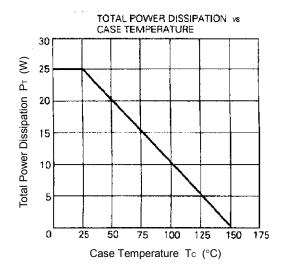
Marking	М	L	К	
h _{FE2}	100 to 200	150 to 300	200 to 400	

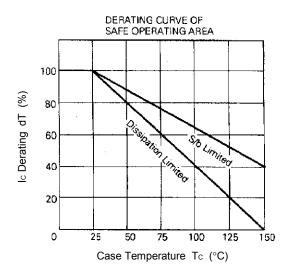
SWITCHING TIME TEST CIRCUIT

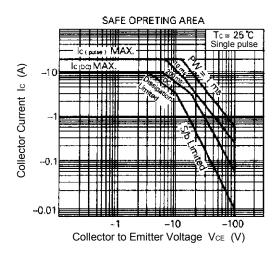


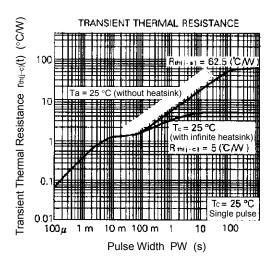


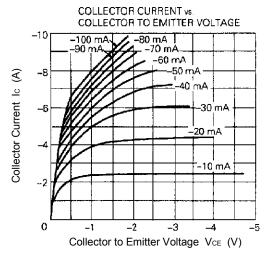
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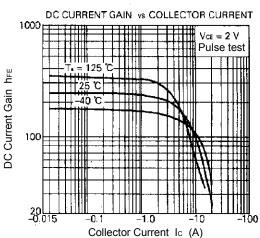








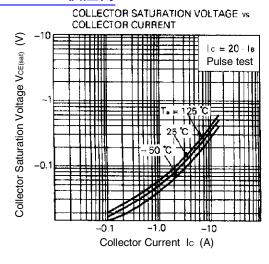


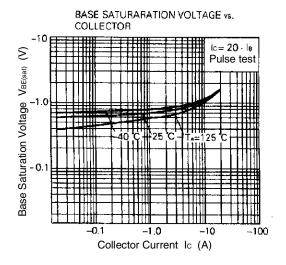


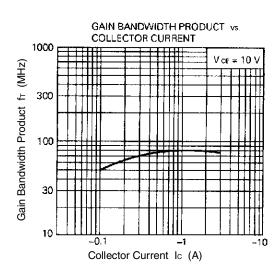
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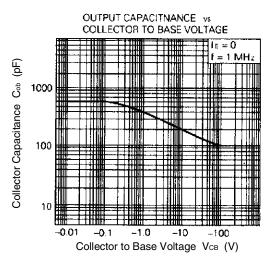


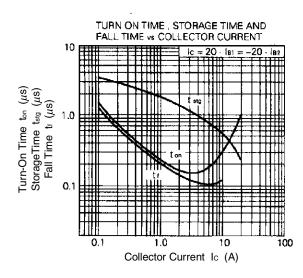
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